

Effective Mass for Holes in Paramagnetic, Plasmonic Cu₅FeS₄ Semiconductor Nanocrystals

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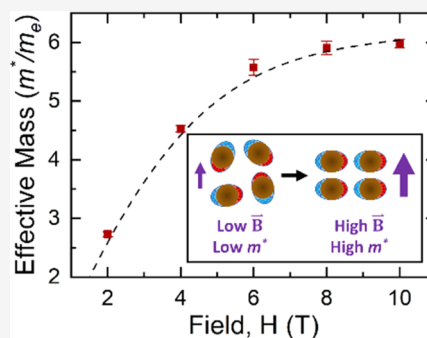
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ABSTRACT: The impact of a magneto-structural phase transition on the carrier effective mass in Cu₅FeS₄ plasmonic semiconductor nanocrystals was examined using magnetic circular dichroism (MCD). Through MCD, the sample was confirmed as p-type with variable-temperature studies from 1.8–75 K. Magnetic field-dependent behavior is observed, showing an asymptotic behavior at high field with an m^* value 5.98 m^*/m_e at 10 T and 2.73 m^*/m_e at 2 T. Experimentally obtained results are holistically compared to SQUID magnetization data and DFT calculations, highlighting a dependency on vacancy-driven polaronic coupling, magnetocrystalline anisotropy, and plasmon coupling of the magnetic field, all contributing to an overall decrease in the hole mean free path dependent on the magnetic field applied to Cu₅FeS₄.



INTRODUCTION

At the nanoscale, plasmonic materials exhibit a strong localized surface plasmon resonance (LSPR) associated with the oscillation of the Fermi level carriers which induces a large electric field at the nanomaterial surface. Noble metals are the prototypical standard for research on LSPR^{1–4} but are typically limited to the visible region.⁵ Plasmonic semiconducting nanocrystals (PSNCs) exhibit a plasmon feature that can be systematically tuned from visible to mid-IR frequencies by controlling the carrier density.⁶ The tunability of the PSNC LSPR is advantageous for surface-enhanced Raman scattering,⁷ refractometric sensing,⁸ and photocatalysis.⁹ In PSNCs, the frequency of the LSPR is highly sensitive to the number of free carriers and the effective mass of the carriers, as modeled using the simplified Drude model, wherein the plasma resonance frequency (ω_p) (eq 1)

$$\omega_p = \sqrt{\frac{ne^2}{m^* \epsilon_0}} \quad (1)$$

is assumed to be primarily dependent on both the free carrier density (n) and carrier effective mass (m^*), where e is the elementary electron charge and ϵ_0 is the vacuum permittivity constant.¹⁰ The carrier mass is dependent on orbital coupling, will be affected by interband levels, and is impacted by vacancies, surface scattering, and lattice defects. While the high surface area in nanocrystals can influence the measured m^* , for simplicity, the carrier mass is typically assumed to be invariant, allowing the plasmon frequency to be predictive of carrier densities. This assumption is reasonable if the only variable is carrier density at a fixed composition and size. The relative

difficulty of measuring m^* independently for PSNCs is likely what has led to using the assumption of a constant m^* .¹¹

In a recent study, it was demonstrated using carrier titration methods that the Drude model underpredicts carrier levels, most likely due to the assumption that the carrier mass is unchanged by the nanoenvironment.¹² Incorporating a p- or n-type dopant into a semiconductor leads to changes in the Fermi level, often accompanied by perturbation of the electron–electron and electron–phonon interactions for a simple valence band (VB)–conduction band (CB) energy structure.^{13,14} In such systems, the Drude model will produce a linear trend in LSPR frequency with carrier density as long as vacancies or site occupation changes do not perturb the system. Results from Sn:In₂O₃ and M:ZnO (M = Al, Ga, In) show the flaw in ignoring the environment at high carrier concentrations, as site occupation effects lead to charge compensation and deviation from parabolic band theory.^{15,16} In these studies, the role of a damping term (Γ), as described within the Jung and Peterson model, was proposed to account for the deviation and assumed to be dependent on energy-level parabolicity, in analogy to the recently explored InN system.¹⁷ A change in parabolicity will lead to a change in carrier effective mass. A perturbation of carrier mass at small PSNCs size is not surprising, as the carrier mass will be

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strongly influenced by scattering, vacancies, and changes in band structure due to surface termination of the nanocrystal.^{11,18–21} Clearly, independently measuring m^* and n from experimental data is critical to evaluate the plasmonic field effects in PSNCs accurately.

While many of the PSNCs studied to date are binary or doped binary wide band gap materials,⁶ a recent report on the ternary, p-type Cu_xFeS_4 , otherwise referred to as bornite, has revealed deviation from the simple Drude approximation.²² Cu_xFeS_4 is an intermediate band semiconductor (IBSC), where Fe d-levels occupy the intermediate band states. IBSC systems are increasingly being explored for their thermoelectric properties. They are typically viewed as indirect band gap materials and are expected to be useful for conversion between heat and electricity, photovoltaics, and LEDs.^{23–25} The bornite family of PSNCs is of interest for plasmonic systems due to bornite PSNCs' low elemental cost, low toxicity,^{26,27} and a biologically transmissive plasmon frequency that is preliminarily an ideal candidate for *in vivo* biomedical applications.²⁸

Early studies on nanocrystal bornites have shown the LSPR is invariant with Cu-to-Fe ratio. It was initially hypothesized that changes in the Cu-to-Fe ratio would tune the band filling and thus the LSPR frequency, but experimentally this is not observed. However, a significant LSPR frequency shift is observed by chemical titration, indicating the extinction features to be carrier density-dependent, as expected by the Drude model.²² The experimental data suggests compensatory effects. These effects differ depending on the Cu-to-Fe ratio and are predicted through a frequency-independent fitting of the Drude model. This results in quantitative damping terms and different effective masses calculated based on the Cu-to-Fe ratio. Cu_3FeS_4 (5:1) bornite nanocrystals exhibit a magnetostructural phase transition with a complex spin reorientation, leading to antiferromagnetic (AFM) interactions.²⁹ The onset of the transition results in an anisotropic structure that impacts the plasmon properties of this PSNC.

The presence of carriers at an LSPR frequency matching the d-band levels influences the carrier effective mass by changing the electron–electron coupling between the LSPR and d-levels. To date, only limited studies on IBSCs have been reported, such as computational studies on Cu_3MCh_4 ($M = \text{V}, \text{Nb}, \text{Ta}; \text{Ch} = \text{S}, \text{Se}, \text{Te}$)^{30,31} and experimental work on CuFeS_2 ^{32,33} and Cu_3VS_4 .³⁴ More extensive studies exist for LSPR behavior on Cu chalcogenide direct band gap systems such as $\text{Cu}_{1.96}\text{S}$ and Cu_{2-x}Se .^{35,36} The perturbation of the carrier mass in nanocrystals has been reported in p-type binary chalcogenides. In Cu_{2-x}Se , the effective mass is observed to be $0.39 m^*/m_e$ in bulk. However, $0.89 m^*/m_e$ is determined for nanodisks,³⁵ while $\text{Cu}_{1.96}\text{S}$ is observed to have an effective mass of $0.8 m^*/m_e$, also for nanodisks.³⁶ Why the carrier mass is perturbed in a nanocrystal has not been fully investigated, and neither has the impact of interband levels on carrier behavior experimentally. This highlights a large gap in the understanding of IBSCs that remains to be filled. This work aims to contribute to filling the gap, as the carrier mass directly impacts carrier mobility for electronic applications and the dampening rate of the plasmon, which affects optoelectronic applications.

In this study, the value of m^* is evaluated for 5 ± 1.4 nm spherical, oleic acid-passivated Cu_3FeS_4 PSNCs, the stoichiometric bornite. Variable-field (± 10 T) magnetic circular dichroism (VH-MCD) experiments were performed at 40 K to evaluate m^* in the bornite nanocrystal, supplemented with variable-temperature (VT-MCD) experiments from 1.8–75 K

measured at 10 T on dropcast thin films of the Cu_3FeS_4 . Fitting of the VH-MCD spectra revealed a larger than expected m^* for Cu_3FeS_4 of $2.73 m^*/m_e$ at 2 T. An unexpected change in m^* was observed with increasing field, with a nearly asymptotic value of $5.98 m^*/m_e$ found at 10 T. The observed value of m^* can be understood by the combined contribution of interband polaronic type coupling to the Fe d-bands, magnetocrystalline anisotropy, and light coupled magnetic anisotropy enhancement caused by direct excitation of the LSPR. The effects reduced the overall mean free path of the hole carriers, thereby resulting in the increased m^* value observed for Cu_3FeS_4 . Additionally, magnetocrystalline anisotropy is expected to perturb the electronic and magnetic properties due to a low-temperature Cu_3FeS_4 crystal structure.

MATERIALS AND METHODS

Copper (II) acetylacetonate ($\text{Cu}(\text{acac})_2$, 97%), iron (III) acetylacetonate ($\text{Fe}(\text{acac})_3$, $\geq 99.9\%$), 1-dodecanethiol (DDT, $\geq 98\%$), oleic acid (OA, technical grade, 90%), oleylamine (OLA, technical grade, 70%), and poly(lauryl) methacrylate in toluene (PLMA, 25%) were purchased from Sigma-Aldrich. Tetrachloroethylene (TCE, 99.0%) was purchased from Beantown Chemical. Quartz glass substrates were sourced from GM-Quartz, while VGE-7031 varnish was sourced from Lake Shore Cryotronics, Inc. Size #4 gelatin capsules for SQUID measurements were obtained from Electron Microscopy Sciences.

Synthesis of Cu_3FeS_4 Nanocrystals. Cu_3FeS_4 PSNCs were prepared following previously reported methods.²² Briefly, $\text{Cu}(\text{acac})_2$ (261.8 mg, 1.0 mmol) and $\text{Fe}(\text{acac})_3$ (70.63 mg, 0.2 mmol) (Cu/Fe ratio of 5:1) were dissolved in 6.7 mL of oleic acid in a three-neck flask under Ar. After heating the solution to 180 °C, 1.5 mL of dodecanethiol was rapidly injected, followed by a 5 min drop-by-drop addition of a solution of sulfur dissolved in oleylamine (0.2 M, 15 mL). The reaction was maintained at 180 °C for 5 min and cooled to room temperature. The Cu_3FeS_4 was transferred to a glovebox after it had reached room temperature and stored under an Ar atmosphere. ICP-MS analysis verified the 5:1 ratio of Cu to Fe. TEM analysis confirms the formation of spherical 5 ± 1.4 nm nanoparticles, and p-XRD analysis matches the high cubic bornite phase commonly seen at higher temperatures.³⁷ (Figure S1)

Linear Absorption Spectroscopy. Cu_3FeS_4 PSNCs were suspended in TCE and diluted until an LSPR absorption of approximately 1.0 absorbance was obtained. UV–vis–NIR measurements were collected in a 1 cm NIR optical cell (Spectrocell) on a PerkinElmer Lambda 950 spectrophotometer. Spectra were baseline-corrected using neat TCE and normalized to the band-edge absorption of the PSNCs. Additionally, samples were dropcast onto quartz substrates, verified by the Lambda 950 spectrophotometer at room temperature before cryostat insertion, and scanned via linear absorbance at 40 K within the cryostat.

MCD Sample Preparation. Thin films of Cu_3FeS_4 nanocrystals were prepared by dropcasting the colloidal TCE solution onto a quartz substrate. Poly(lauryl) methacrylate (PLMA) was added as a binder to assist with adhesion to the substrate. Concentration was controlled and monitored by checking the sample substrate using a Lambda 950 UV–vis–NIR spectrometer until an optimal absorbance of approximately 1.0 is obtained. Afterward, VGE-7031 varnish was used

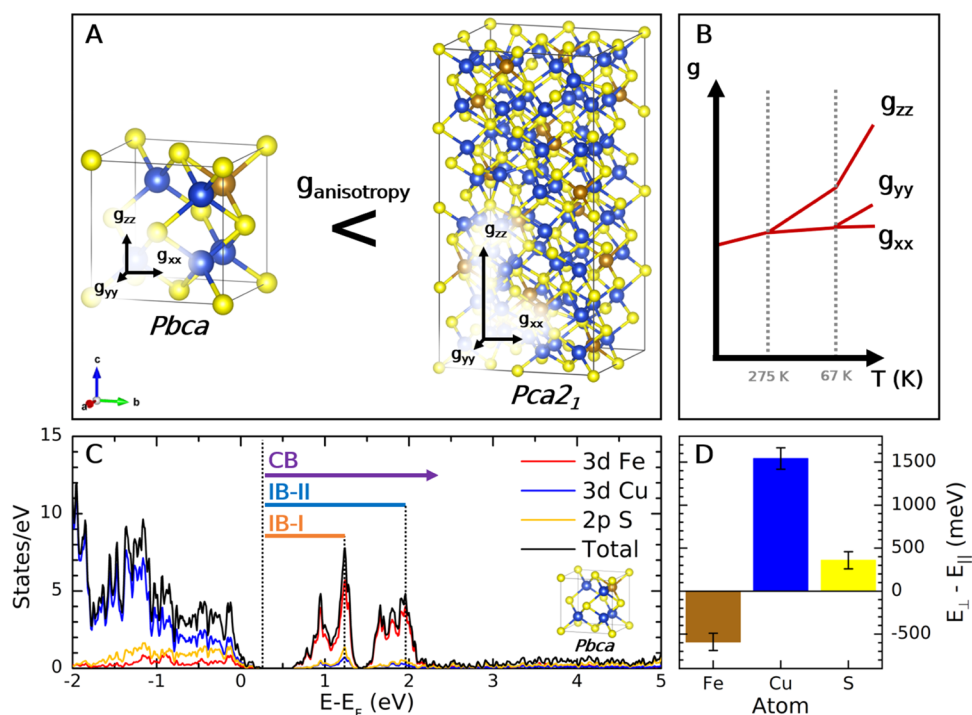


Figure 1. Theoretical Investigation of Cu_5FeS_4 . (A) Cubic Cu_5FeS_4 unit cell used in calculations for this work is compared to the low-temperature $Pca2_1$ phase⁴¹ with expected g -factor vector differences. Sulfur atoms are yellow, copper blue, and iron brown. (B) Expected g -factor splitting behavior as a function of temperature with a breaking of symmetry initially occurring at 275 K for $Pbca$ and then occurring again at 67 K for $Pca2_1$. (C) Representative DOS plot identifying high probability electronic transitions and showing the expected IBSC structure. (D) DFT calculations were used to calculate magnetic anisotropy energy (MAE) for perpendicular versus parallel magnetic moment orientations for the unit cell and broken down by atomic differences.

to adhere the substrate onto an optical probe for use in the cryostat.

Variable-Field (± 10 T at 40 K) Magnetic Circular Dichroism (VH-MCD). The variable-field VH-MCD is performed on the Cu_5FeS_4 sample dropcast onto a 0.5 in quartz substrate. The sample was dried under vacuum prior to insertion into an Oxford Instruments 10 T HelioxTL Superconducting Spectromag. A Newport Quartz Tungsten Halogen Lamp (Model 70050) with a monochromator (Model 69931) and optical chopper operating at a frequency of 211 Hz was used in combination with a ThorLabs Glan–Taylor linear polarizer (GLB-10) to linearly polarize incident light, followed by use of a HINDS Instruments photoelastic modulator (PEM-100) for subsequent circular polarization at 47 kHz. Two Stanford Research Systems SR830 lock-in amplifiers were phase-locked to the chopper and PEM frequencies to maximize the signal-to-noise for the DC detector spectrum (V_{DC}) and ΔA signal (V_{AC}) obtained, respectively. A Thorlabs biased Si photodetector (DET10A) and a biased InGaAs detector (DET20C2) were used interchangeably to select for visible and NIR regimes, respectively, and amplified with a Femto current amplifier (LCA-200K-20M). Temperature was monitored and controlled through a Keck clamp fiber cable routed through the sample probe and mounted adjacent to the sample substrate. A positive and negative field sweep scan from 0–10 T was performed for the bornite samples at 40 ± 1 K in 2 T intervals. The reported spectra were corrected by subtracting the 0 T scan to eliminate artifacts from polarization effects, magnetic field inhomogeneity, and other disturbances that may arise during MCD measurement. To confirm polarization of the experimental setup, a 6.2 nm gold nanoparticle solution

was compared to a cast film of Au NP measured in the sample cavity of the cryostat versus the fringe field (for reference, the field reduction at the outer window is 10 to 6T and follows an exponential decay with distance) of the cryostat. The experimental calibration results agree with published data³⁵ and confirm the experimental setup is properly corrected. (Figure S2). Positive and negative field magnetic vector directions were confirmed through the use of a right circularly polarized film to identify whether to subtract positive field data from negative or negative from positive when performing the difference measurements in the Faraday configuration.

Variable-Temperature (1.8–75 K at 10 T) Magnetic Circular Dichroism (VT-MCD). The same experimental setup used for VT-MCD measurements was used: while holding the applied magnetic field at +10 T, the temperature was swept from a minimum temperature of 1.8 to 75 K, where three scans were taken at each temperature point and averaged utilizing the InGaAs NIR detector to measure C-term contributions at and near the LSPR feature.

VH-MCD Effective Mass Fitting. From the spectra, experimental absorption spectra are used as the basis for a rigid-shift simulation of LCP and RCP absorption as a function of E_z to fit the experimental VH-MCD spectra. The simulated MCD fit is optimized by a custom Python code at each field, allowing for the direct measurement of E_z and m^* at every measured magnetic field, thereby increasing the accuracy and robustness of MCD measurements. The acquisition of m^* through MCD itself is not novel; however, the acquisition through comparison by RS approximation of a corresponding absorption spectrum is nontrivial.³⁵ The novelty originates from the spectral range and standardization of data analysis,

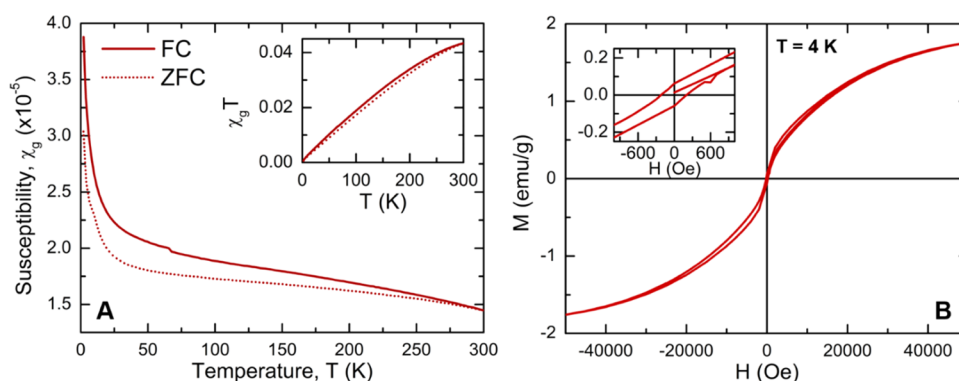


Figure 2. Magnetic Data of Cu_5FeS_4 PSNCs. (A) Magnetic susceptibility measurements show a high degree of coercivity between FC and ZFC curves, with the previously reported antiferromagnetic transition at 67 K⁴¹ observed as a discontinuity. Additionally, the majority of linear behavior seen in χT (A, inset) indicates the presence of long-range antiferromagnetic ordering. (B) Magnetization measurements were performed at 4 K, showing a narrow hysteresis loop that indicates weak coercivity approaching the single domain, superparamagnetic regime for the Cu_5FeS_4 PSNCs.

which allows for multiple collections of m^* from only one experimental MCD run, which sweeps through various magnetic field strengths, and every field integer can subsequently be treated as its own experiment. Simulated MCD spectra are calculated using the `Scipy.optimize.curve_fit()` Python function utilizing the trust region reflective algorithm to provide a simulation of best fit using E_z as the dependent variable for minimization. The python code used is publicly available at <https://github.com/strouselabgithub/strouselab>.

Superconducting Quantum Design MPMS SQUID Magnetometry. Field and Temperature sweep SQUID magnetometry was performed on Cu_5FeS_4 diluted in eicosane (1:10 mg) and loaded as a powder in gel capsules. The dilution in eicosane is to minimize particle–particle interactions. Magnetization data was collected at 4 K from -50 to 50 kOe, while magnetic susceptibility data was recorded at 1 kOe for field sweep and no field for the zero-field sweep measurements from 2–300 K.

Computational Details. DFT + U calculations were performed to simulate the projected density of states for Cu_5FeS_4 utilizing the open-source Quantum ESPRESSO repository.³⁸ A single unit cell of Cu_5FeS_4 was initialized with lattice constants of 5.475 Å, similar to prior literature.³⁷ Plane augmented wave pseudopotentials were used in addition to unrestricted DFT + U, as was used previously for CuFeS_2 .³² Self-consistent field calculations were performed on a relaxed structure with a Monkhorst k-point mesh of $6 \times 6 \times 6$ to maximize sampling across the dielectric field of the Brillouin zone.³⁹ This was followed by a non-self-consistent field calculation of $12 \times 12 \times 12$ for the simulated projected density of states. Simulated absorption spectra and transitions of interest were acquired by diagonalizing and solving for allowed transitions after calculating the density of states (DOS). Magnetic anisotropy energy (MAE) was calculated using the Force Theorem method⁴⁰ by comparing the total energy of the system under perpendicular and parallel magnetic orientations.

RESULTS AND DISCUSSION

Bulk 5:1 bornite exhibits a second-order magnetic–structural phase transition at 67 K that is coupled with a structural phase transition from $Pbca$ to $Pca2_1$ resulting in a loss of higher-order symmetry at $T < 67$ K.^{41,42} The second-order transition in the bulk sample is described as a RT paramagnetic-to-low-

temperature antiferromagnetic (PM-AFM) transition but can be thought of as a spin glass transition due to spin reordering. The structural shift from $Pbca$ to $Pca2_1$ will induce changes in g-factor tensors, as shown in Figure 1A. The presence of the structural-magnetic phase transition leads to a complex spin-ordering event, causing increased magnetocrystalline anisotropy reminiscent of a Bose–Einstein condensate.⁴³ The increased anisotropy will impact carrier mass, as seen in the anisotropic crystal structure of anatase TiO_2 .⁴⁴ In the case of 5:1 bornite, this will be dependent on the strength of the applied magnetic field, leading to anomalous Zeeman splitting for the electronic transitions. This can be explained as resulting from the nonlinear g-factor changes occurring as a function of decreasing temperature and modeled after the changes in unit cell parameters observed by Rietveld refinement.⁴¹

Computational Predictions. In Figure 1, the impact on the electronic levels of the $Pbca$ to $Pca2_1$ structural change for 5:1 bornite (Figure 1A) can be evaluated by considering the anticipated splitting of the electronic levels in a magnetic field (Figure 1B). The change in energy with the field can be rewritten in terms of the anisotropic g-values (eq 2)

$$g = (g_{xx}^2 \sin^2\theta \cos^2\phi + g_{yy}^2 \sin^2\theta \sin^2\phi + g_{zz}^2 \cos^2\theta)^{1/2} \quad (2)$$

In the case of the $Pca2_1$ structure, when only considering lattice parameters, $g_{xx} \neq g_{yy} \neq g_{zz}$. Schematically, this is represented in Figure 1B and illustrates the importance of considering the evolution of g-factor contributions under a magnetic field as a function of temperature. In the case of 5:1 bornite, as temperature decreases, the disparity in anisotropic g-values increases and directly correlates to a rise in magnetocrystalline anisotropy that should be observable experimentally.

Figure 1C,D presents the predicted electronic structure and magnetocrystalline anisotropy as the calculated projected density of states (DOS) and magnetic anisotropy energy (MAE). The MAE and DFT calculations were performed on a reduced unit cell (Figure 1A) using Quantum ESPRESSO density functional theory (DFT) self-consistent field calculations.³⁸ Consistent with literature precedent,⁴⁵ the 5:1 bornite has a band gap of approximately 2.09 eV with two intermediate band gaps of 0.22 and 1.12 eV associated with Fe tetrahedral d-level splitting. The Fermi level beneath the valence band edge (Figure 1C) also agrees with the assignment

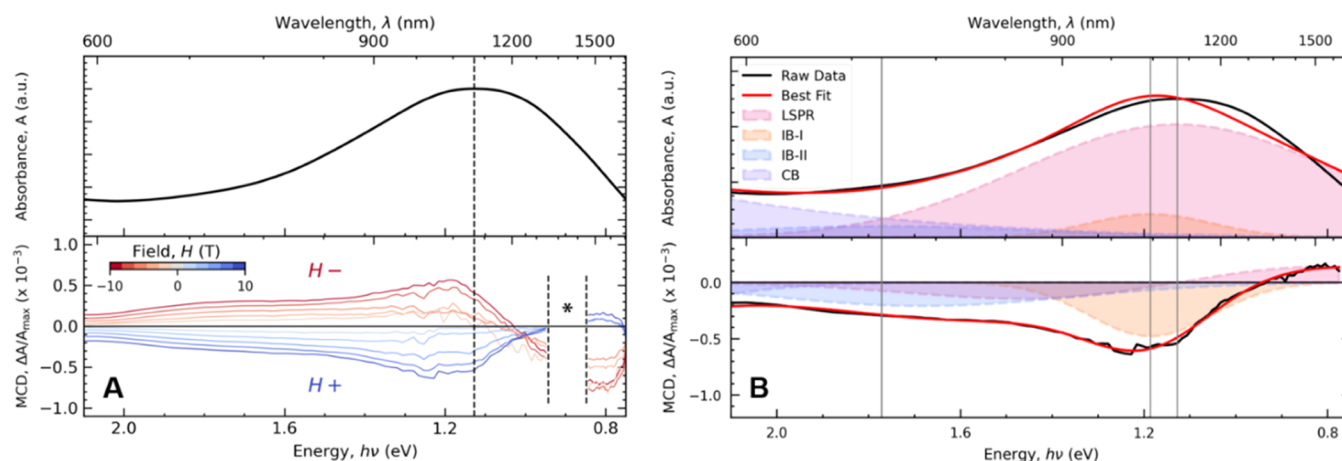


Figure 3. Magneto-optical data of Cu_3FeS_4 PSNCs. (A, top) Characteristic 40 K linear absorption spectrum of 5 nm Cu_3FeS_4 is shown with an LSPR extinction feature observed at 1.1 eV and indirect band gap at 2.1 eV paired with (A, bottom) VH-MCD data taken for Cu_3FeS_4 , where the VH-MCD data is merged from a visible Si detector and a near-infrared InGaAs detector. The LSPR peak observed in linear absorption is slightly higher in energy compared to the inflection point observed in the VH-MCD spectra (1.1 vs 1.0 eV as denoted by the dashed line). A discontinuity in data for the VH-MCD data is removed at 0.9 eV marked by the asterisk attributed to a characteristic transmission dip observable in Spectrosil B windows. The full, unmodified spectra can be found in Figure S3. (B, bottom) MCD Data at 10 T is deconvoluted by several probable electronic transitions observed in the previously performed DOS calculations. (B, top) Subsequently, the linear absorption is reconstructed utilizing the same transition energies and FWHM, letting the amplitude float as the spectra is fitted with the `Scipy.optimize.curve_fit()` least-squares fitting algorithm. Gray vertical lines mark the various transitions assigned.

of a p-type IBSC system. Hybridization between Cu-3d and S-2p is evident in the valence band in the DOS.

To calculate the MAE, Quantum ESPRESSO uses ultrasoft pseudopotentials in the generalized-gradient approximation selected through the standard solid-state pseudopotential library^{46–48} to generate a semi-quantitative understanding of MAE utilizing the Force Theorem method.⁴⁰ This allows the total electronic band energy to be differentiated between perpendicular and parallel magnetic dipole moments. The value of the full MAE is 2.14 eV on average between the Fe(III) atom and the averaged Cu(I) atoms. Cu shows the greatest deviation in magnetic dipole moment, favoring a parallel magnetic dipole, while Fe favors a perpendicular magnetic dipole orientation. While S should possess no magnetic moment, it is hypothesized that an MAE is experienced for these atoms due to orbital hybridization of the Cu-3d with S-2p, as observed in the DOS. The observed hybridization is expected to introduce magnetic coupling between these two electronic states in the form of p–d orbital exchange coupling.⁴⁹ As the observed extinction feature in an LSPR mode is reflective of the imaginary and real component crossing of the dielectric function, it is anticipated the LSPR mode will be impacted by the magnetic anisotropy, especially considering the carriers originate from Fe vacancies.⁴⁵

Magnetic Properties. In Figure 2A, the onset of antiferromagnetic (AFM) order is observed as a discontinuity at 67 K in temperature-dependent magnetic susceptibility (2–300 K) measurements using a superconducting quantum interference device (SQUID). The inset of Figure 2A shows a strong linear trend up to 300 K for the χT data, indicating typical paramagnetic behavior associated with the DOS projected Fe-3d intermediate band level.^{22,45} The field sweep data and zero-field-cooled (ZFC) vs field-cooled (FC) temperature sweep data reveal the 5:1 bornite is magnetic with increased coercivity as temperature decreases for Cu_3FeS_4 . The assignment of an AFM magnetic transition at the magnetic susceptibility discontinuity agrees with prior bulk

bornite experiments, where collinear AFM ordering of spins, parallel and antiparallel to the *b*-axis, was reported at $T_N = 67.5$ K. Ferrimagnetic order appearing below 35 K was associated with charge ordering.^{42,50–52} In the bulk bornite, a fluctuation of the spins below 140 K associated with Fe and Cu is observed to produce a magnetic moment with spin orientation that changes due to valence fluctuations. The second-order phase transition at 67.5 K couples the magnetic and lattice (*Pbca* to *Pca2₁*) elements, resulting in a structural dependence of electron exchange via the induced crystalline anisotropy following the transition. The structural transition results in a superparamagnetic relaxation, leading to a loss of higher-order symmetry, increasing magnetocrystalline anisotropy in the 5:1 bornite.⁵³ The magnetic and structural properties are associated with temperature-dependent intervalence charge fluctuation ($\text{Fe}^{3+/2+}$, $\text{Cu}^{2+/1+}$) in the 5:1 stoichiometry below 140 K.

Consistent with the MAE and magnetic measurements, the 5:1 bornite PSNC is anticipated to have a large magnetocrystalline anisotropy caused by the loss of crystallographic symmetry. As the bornite PSNCs themselves are spherical, shape anisotropy is precluded from contributing significantly and is not considered here. The coercivity at 4 K is 200 Oe and saturated magnetization, M_{sat} is 1.8 emu/g. However, this is likely due to nearing the superparamagnetic regime for these nanocrystals, as they are well within the typical size regime of <10 nm.⁵⁴ Utilizing eqs 3 and 4, the effective magnetic anisotropy, K_{eff} , and superparamagnetic diameter threshold, D , can be estimated utilizing the observed blocking temperature, T_b , of 299 K and calculating for the volume, V , of a typical 5 nm nanocrystal

$$T_b = \frac{K_{\text{eff}}V}{25k_B} \quad (3)$$

$$D = \sqrt[3]{\frac{31k_B T}{K_{\text{eff}}}} \quad (4)$$

where k_B is the Boltzmann constant and T is the temperature. For Cu_5FeS_4 , a K_{eff} of 0.197 MJ/m³ and D of 1.58 nm at 4 K are predicted for Cu_5FeS_4 , agreeing with the experimental data observed.

Optical Properties. As shown in Figure 3, the p-type Cu_5FeS_4 PSNC exhibits a well-defined LSPR at 1.1 eV. Our previous publication evaluated the LSPR using the Drude model approximation. We concluded that the carriers arose from Fe vacancies with a Drude model-predicted effective mass of 1.4 m^*/m_e at RT.²² As the temperature decreases, carrier mass is expected to increase with the lattice valence ordering. Assuming the onset of AFM order is the same as the reported bulk bornite, charge fluctuation is anticipated to strongly influence the effective carrier mass and thus plasmon properties below 140 K, leading to nonlinear Zeeman effects.^{51,55} The effect of the magnetic field on the carrier mass can be evaluated using MCD below the magnetic phase transition to calculate the effective carrier mass (m^*) from the cyclotron resonance frequency,³⁵ as MCD exploits two magneto-optical phenomena in tandem, cyclotron resonance and the Zeeman effect, both of which are described in previous literature with respect to MCD.^{56–58} Evaluating the field-dependent change in m^* above and below the AFM ordering temperature in the 5:1 bornite PSNC should allow carrier density changes expected to occur with valence ordering in the anisotropic low-temperature 5:1 crystal lattice to be simulated using the Drude model.

MCD is useful for its sensitivity to site-specific metal contributions in a given material.⁵⁹ MCD has been previously used to elucidate fine structures that may appear in optical features such as band gap absorption edges in semiconductors, intra-atomic transitions, and LSPRs.^{60–62} The MCD spectra are plotted as the difference spectra (ΔA) of left circularly polarized light (LCP) absorption subtracted from right circularly polarized light (RCP) absorption, where LCP is selective for $\Delta M_j = +1$ while RCP is selective for $\Delta M_j = -1$. These selection rules allow for energy shifting in the LCP and RCP absorption spectra.⁵⁷ The difference in energy for LCP and RCP absorption for spin levels of the electronic system is termed the Zeeman effect. The magnitude of the Zeeman effect is contingent on the degree of splitting proportional to magnetic field strength rather than originating from a property intrinsic to the material itself, such as chirality for circular dichroism. The Zeeman effect is represented by the splitting of the electronic energy level induced by the application of an external magnetic field, represented mathematically as (eq 5)

$$E_Z = g u_B M_j \vec{B} \quad (5)$$

where g is the g -factor, u_B is the Bohr magneton, M_j is the total angular momentum, and \vec{B} is the total magnetic flux in the material.⁵⁷ The Zeeman splitting energy (E_Z) is fundamental to magneto-optical spectroscopy and allows for the observation of electronic transitions that would otherwise be impossible for traditional optical techniques. The carrier type (n or p) is evaluated by inspection of the sign of the LCP absorption feature, with p-type showing a positive LCP and n-type exhibiting a negative LCP feature.

By assuming Born–Oppenheimer, Franck–Condon, and rigid-shift (RS) approximations, the ΔA MCD spectrum can be deconvoluted into three constituent shapes classified as A_1 , B_0 , and C_0 terms (eq 6)⁵⁶

$$A_1 : B_0 : C_0 = \frac{1}{\Gamma} : \frac{1}{\Delta E} : \frac{1}{k_B T} \quad (6)$$

where Γ is the absorption feature linewidth magnitude, ΔE is the zero-field state separation magnitude, k_B is the Boltzmann constant, and T is the temperature.⁵⁶ The A_1 -term originates from the lifting of degeneracy in the nearest excited state due to Zeeman splitting directly proportional to the magnetic field applied to the sample. A_1 -term effects are broadly identifiable from their derivative-shaped curve, where both a positive and negative feature will be present in the differential spectrum. A_1 -terms are extremely useful for determining the precise energy level of an electronic orbital at zero-field by examining where inflection points appear. The B_0 -term is unique because it arises from the population mixing of neighboring, non-degenerate excited states at zero-field. As a magnetic field is applied, the change in the mixing of populated states accounts for differences observed in a B_0 -term feature. C_0 -term effects could be considered an opposite process relative to the A_1 -term, as nondegeneracy arises in the ground state of an electronic transition under an applied magnetic field. In 5:1 bornite PSNCs, the magneto-structural phase transition will lead to crystalline anisotropy and a magnetic ground state, resulting in A_1 - and C_0 -term contributions to the MCD spectra. C_0 -term contributions are typical in paramagnetic systems.⁵⁶

In Figure 3, linear absorption and variable-field MCD (VH-MCD) from 10 to -10 T are measured on dropcast films of Cu_5FeS_4 at 40 K between 600 and 1700 nm, as seen in Figure 3A and B, respectively. The experimental data is collected on substrate-cast films inserted into a He-cryostat and requires separate data collection regions due to limits in spectral sensitivity of the detectors available. The MCD spectra are plotted as the measured difference ($\Delta A/A_{\text{max}}$) between LCP and RCP spectra. A transmission dip at 0.9 eV is attributed to a small absorption in Spectrosil B Quartz which, while not visible in the linear absorption, is likely due to the lower signal and sensitivity of the VH-MCD data. In Figure 3A, the MCD inflection is not centered on the LSPR peak. The offset may be due to underlying overlapping transitions with different Zeeman energies or, more likely, inter-particle coupling in the cast film, as observed in gold plasmonic nanomaterials.^{63,64}

For the linear absorption compared with previously performed colloidal solution measurements,²² an overall increase in inter-particle scattering is observed for Cu_5FeS_4 , coincident with an increase in the FWHM. Across multiple samples prepared using various dropcasting methods, the observed thin-film spectra are consistent and reproducible, pointing to a real change in the dielectric function. Fitting the frequency-independent simplified Drude model utilizing the MATLAB code from Milliron and co-workers¹⁰ was used to quantify these observed differences in terms of the plasma frequency (ω_p) and damping term (Γ) for Cu_5FeS_4 , using 3.48 as the dielectric constant of Cu_5FeS_4 ,⁵⁵ as shown in Figure S4 in the Supporting Information. The changes in the frequency and damping contributions between temperatures are quantified by subtracting the room temperature fits from the 40 K results, where $\text{Cu}_5\text{FeS}_4(\Delta\omega_p) = 1201.7 \text{ cm}^{-1}$, $\text{Cu}_5\text{FeS}_4(\Delta\Gamma) = 5791.14 \text{ cm}^{-3}$. These results show that the damping observed in the dropcast Cu_5FeS_4 sample is significantly greater compared to the colloidal solution, supportive of an increase in overall inter-particle effects, donor level scattering,⁶⁵ or changes in the local dielectric.

Table 1. MCD and Absorption Fitting Parameters

peak assignment	energy (eV)	A_1 (C_0)/D	B_0 /D (eV^{-1})	Abs FWHM (eV)	Abs amplitude (a.u.)
LSPR	1.12	-8.29×10^2	---	0.8	0.409
IB-I	1.19	-3.89×10^1	-9.76×10^3	0.32	0.086
IB-II	1.77	2.02×10^3	-8.52×10^3	0.76	0.041
CB	3.44	3.70×10^4	-9.18×10^{-3}	1.01	0.186

The VH-MCD spectra in Figure 3A can be evaluated in terms of the A_1 - (Zeeman term), B_0 - (field-induced state mixing), and C_0 - (ground state degeneracy due to paramagnetic state) terms (eq 7).

$$\frac{\Delta D_{\text{MCD}}(E)}{E} = \gamma \left\{ A_1 \left(-\frac{df(E)}{dE} \right) + \left(B_0 + \frac{C_0}{kT} \right) f(E) \right\} (\mu_B H) cz \quad (7)$$

where $\Delta D_{\text{MCD}}(E)$ is the MCD spectrum, $E = h\nu$ for photon energy, γ is an oscillator strength constant, $f(E)$ is the linear absorption spectra normalized by area, $k_B T$ is the Boltzmann constant and temperature product, μ_B is the Bohr magneton, H is the field strength, c is the concentration, and z is the pathlength.^{58,66} The 5:1 bornite is magnetic and may have C_0 -term contribution. The coupled structural and magnetic phase transition below 67 K may impact the value of C_0 . It is anticipated that the ratio of $A_1/B_0/C_0$ is the same as in eq 6 (1:10:200 for this experiment at 40 K).⁶⁷ The temperature dependence of the MCD signal for the LSPR band and IB-I was measured at 10 T from 75–1.8 K to evaluate the magnitude of the C_0 contribution (Figure S5). As the second-order magneto-structural phase transition occurs at 67 K, it is anticipated that a temperature-dependent MCD response may be observable from 75–1.8 K, reflecting the onset of spin-carrier interactions. The lack of MCD spectral change with temperature in the phase transformation region at 10 T suggests the MCD data is dominated by the A_1 (C_0) and B_0 terms in eq 7 for the 5:1 bornite due to the maximization of magnetic dipole orientation along the high m^* axis at 10 T. At a lower magnetic field, a temperature dependence is expected, as the magnetic dipole is not maximized in one vector orientation; however, further studies are needed to validate this hypothesis.

In Figure 3, the experimental data are fitted to a convolved A_1 : C_0 and B_0 term. The deconvolution of peaks is formed by the summation of a Gaussian curve representing C_0 and B_0 terms and the derivative of a Gaussian curve representing the A_1 term modeled after previous literature.⁶⁶ The assigned electronic transitions in the MCD at 1.12 (LSPR), 1.19 (IB-I), 1.77 (IB-II), and 3.44 (CB) eV are identified through second-order derivation of the linear absorption spectrum in tandem with the most probable computationally identified electronic transitions. For the fits, the normalized transition dipole moments were obtained as indicated previously by Safin et al.⁶⁶ The assumption of a B_0 contribution and a convolved A_1 :- C_0 -term reflect the known magnetic ground state in 5:1 bornite and the difficulty to deconvolve the MCD spectra fully. MCD parameters for the identified transitions are listed in Table 1.

The LSPR and IB-I ($VB \rightarrow d$ -band ($Fe-e_g$)) transitions are dominated by the convoluted A_1/C_0 term contributions (referred to as A_1 term henceforth), while IB-II ($VB \rightarrow d$ -band ($Fe-t_{2g}$)) and CB transitions have A_1 and B_0 -term contributions, indicating that there is a high degree of mixing of energy levels present in these band regions. The B_0 contribution in IB-II reflects the low ΔE of the split t_{2g} level compared to IB-I (Figure 1). The CB exhibits the largest A_1 -

term, reflecting the multitude of excited state transitions that can occur within the CB. The MCD fits show negative A_1 term dichroism for the LSPR and IB-I transitions, while the IB-II and CB show positive dichroism. The negative A_1 -term for the LSPR transition experimentally confirms that the 5:1 sample is a p-type PSNC.^{35,68} The observed opposite dichroism correlates to antiparallel magnetic moments for the Cu 3d and Fe-3d orbitals below the AFM ordering temperature in 5:1 bornite. Fe vacancies are theorized to be the source of free holes in chalcopyrite, $CuFeS_2$, and are suspected of having the same origin for the carriers generating the p-type LSPR for bornite-like semiconductors.^{45,69} The observation of the same dichroism for LSPR and IB-I likely indicates that the carriers are in the IB-I Fe-3d (e_g) bands.

Effective Mass Calculation. From the MCD spectral assignments, m^* can be evaluated using the relationship in eqs 8 and 9

$$m^* = \frac{qB}{\omega_c m_e} \quad (8)$$

$$\omega_c = \frac{2\pi E_z}{c} \quad (9)$$

where ω_c is the cyclotron resonance frequency, q is the elementary charge, B is the magnetic field, m_e is the mass of an electron, E_z is the Zeeman splitting, and c is the speed of light. Assuming the LSPR will obey the RS approximation, as previously reported by Gamelin and co-workers,³⁵ the LCP and RCP spectra will split equally about the LSPR frequency, resulting in the observed MCD spectrum (Figure S6). The field-dependent splitting yields a Zeeman splitting value (E_z) as observed in eq 5.^{57,70} In Figure 4, the Zeeman term as a function of the applied field is plotted and exhibits an

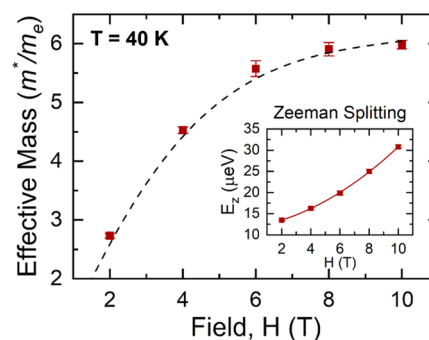


Figure 4. Effective Mass Behavior in Cu_5FeS_4 PSNCs. VH-MCD for Cu_5FeS_4 were fitted with simulated MCD spectra to obtain a Zeeman splitting energy (E_z) for all collected fields at 40 K. Once E_z is calculated, m^* is solved for utilizing a convolution of eqs 8 and 9, where a magnetic field-dependent behavior is observed. A sigmoidal-like increase in m^* is observed until 10 T, where m^* approaches an asymptote of $5.98 m^*/m_e$ and is fitted to a Brillouin function (dotted line), with $S = 1/2$. The raw E_z fit data (inset) is shown to also increase in a nonlinear fashion and is fit to a $5/3$ power law.

asymptotic behavior. The asymptote reflects the field-driven spin orientation of the spin lattice in the 5:1 bornite, consistent with the model developed for bulk bornites.^{42,51}

A plot of the field-dependent m^* for 5:1 bornite is shown in Figure 4. A complete description of the m^* calculation can be found in the Supporting Information. The m^* exhibits a field-dependent effective mass that can be fitted to a hyperbolic cotangent arising from the spin-ordering saturation at high fields, consistent with the SQUID data. The value of m^* exhibits a minimum of $2.73 \pm 0.041 m^*/m_e$ at 2 T and a maximum of $5.98 \pm 0.074 m^*/m_e$ at 10 T. The calculated value for m^* at 2 T is high but not unreasonable for a p-type semiconductor system with intrinsic Fe vacancies present in the crystal structure. As the concentration of vacancies increases, the increase in scattering centers will dampen the carrier mobility and be reflected in the m^* value. Combined with the previously discussed DFT results, as the valence band is primarily composed of S-2p and Cu-3d and IB is composed of Fe-3d, the field-dependent m^* behavior can be correlated and understood through the increased band overlap due to high field Zeeman splitting increasing the degree of the p–d exchange interaction.⁴⁹

When compared to similar Cu-based p-type systems, the m^* values calculated are within reason.⁷¹ For example, Kumar et al. observed an increase in carrier mobility and a subsequent decrease in effective mass through the doping of Se.⁷² Although no bulk measurement of pure Cu_5FeS_4 could be obtained, the nearest ratio $\text{Cu}_5\text{FeS}_{3.9}\text{Se}_{0.1}$ was measured to have an m^* of 2.56. However, with the degree of carrier mobility shift due to Se doping, it is likely that the intrinsic m^* for Cu_5FeS_4 is much higher than what could be effectively measured using the Hall effect. With an observed significant increase in resistivity and decrease in carrier mobility, one would expect the m^* for bulk bornite to be higher than 2.56 m^*/m_e , which corresponds with the directly measured 2 T m^*/m_e from VH-MCD in this paper. Utilizing prior data from bulk Cu_5FeS_4 , a constant carrier relaxation time approximation is used to extrapolate what the undoped Cu_5FeS_4 value may be, utilizing a Se doped system previously published, as shown in Figure S7. From a first-order, linear approximation between m^* and the electron mobility, the predicted m^* for a bulk Cu_5FeS_4 is near 2.71 m^*/m_e under no applied magnetic field, matching surprisingly well to the MCD experimental data. Yet, it does not explain the asymptotic behavior seen as the effective mass rapidly increases with increasing field.

As reported by Pineider, a possibility for the increased m^* value is neighboring electronic interband transitions leading to variation in the local dielectric function.⁷³ From the DFT calculations and literature, interband coupling may impact the local dielectric function.²² However, the interband mixing alone would not account for the observed enhancement of m^* . Previous work with Cu_{2-x}Se , featuring very similar optical absorption and MCD A_1 -term asymmetry, also reported differences in bulk versus nanocrystal m^* due to changes in carrier compensation.³⁵ The observation of a large m^* in anatase TiO_2 is thought to arise from crystalline anisotropy, resulting in differences in carrier mobility along separate axes of the crystal structure.⁴⁴ In Au/Co/Au film nanostructures, excitation of the LSPR under an applied magnetic field resulted in a strengthening of magnetic anisotropy along a given crystallographic axis.⁷⁴ Similarly, the magnetocrystalline anisotropy is anticipated to impact the MCD spectra for 5:1 bornite due to the previously reported magneto-structural

transition at 67 K⁴¹ and photoexcitation from the MCD experiment itself.

The presence of the hyperbolic field-dependent m^* values suggests that a major contributor to the large m^* value is the coupling of the spins on the iron and Cu center to the holes in 5:1 bornite. The stronger coupling at a high magnetic field will lead to a greater degree of phonon–hole coupling to the lattice from the observed magnetocrystalline anisotropy and a greater degree of magnetically coupled carriers experiencing a reduction in mean free path from the applied magnetic field. Additionally, as previously observed in the linear absorption, increased inter-particle interactions between individual bornite PSNCs are expected to increase the degree of phonon–hole coupling and further enhance the observed m^* . The result is an increased value of 5.98 m^*/m_e at fields >8 T. Large g -values have also been reported in dilute magnetic semiconductors due to the carriers coupling to magnetic spin.⁷⁵ By analogy to dilute magnetic semiconductors where the carrier is coupled to spins in the lattice, the field-dependent response of m^* can be fitted to a Brillouin function in eq 10, assuming the relationship of the cyclotron resonance, E_c , and LSPR, such that

$$m^* = \frac{1}{2} N g_s \mu_B \left[(2S + 1) \coth \left((2S + 1) \frac{g_s \mu_B B}{2k_B T} \right) - \coth \left(\frac{g_s \mu_B B}{2k_B T} \right) \right] \quad (10)$$

where N is a fitting parameter, g_s is the Lande' g -factor, μ_B is the Bohr magneton, S is the spin quantum number, B is the magnetic field, k_B is the Boltzmann constant, and T is the temperature. A large g -value (14.3) is extracted from the experimental data fit in Figure 4, assuming $S = 1/2$ and $T = 40$ K. Similar magnetic dependence has been observed previously in dilute magnetic semiconductors⁷⁶ and recently in gold cluster interband transitions, where the thermally driven population of d-band carriers were reported to be involved.⁷⁷ The experimental data supports the coupling of the d-band spins and hole carriers in the 5:1 bornite through the spin-ordering structural transition.

CONCLUSIONS

Cu_5FeS_4 PSNCs were examined by various optical, magnetic, and magneto-optical techniques in tandem to measure the effective mass of bornite directly and explain the origins of the observed field-dependent behavior. DFT and SQUID measurements highlighted that bornite exhibits an antiferromagnetic transition that leads to increased magnetocrystalline anisotropy and a coupling of the d-bands to the hole carriers in the conduction band via a p–d exchange mechanism. The exchange mechanism leads to a field-dependent m^* value that, when fitted to a Brillouin function, yields a large g -value for the LSPR.

The Cu_5FeS_4 nanocrystal is confirmed to be a p-type semiconductor based on the VH-MCD data. The m^* of the LSPR at 1.12 eV in Cu_5FeS_4 was quantified as 2.73 m^*/m_e in the low-field regime and 5.98 m^*/m_e in the high-field regime utilizing high-field VH-MCD. The observed field-dependent m^* behavior was attributed to a substantial decrease in the carrier mean free path due to magnetocrystalline anisotropy, polaronic type coupling with native defects, and LSPR-enhanced magnetic anisotropy. Further work should be done to experimentally validate the anisotropy of m^* proposed in

Cu₅FeS₄, as was previously done for anatase. The observation of an external magnetic field directly influencing the electronic transport properties in Cu₅FeS₄ PSNCs suggests the role of magnetocrystalline anisotropy on carrier transport in plasmonic and thermoelectric materials is under-investigated in nanomaterials.

■ ASSOCIATED CONTENT

SI Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acs.jpcc.2c03459>.

Drude modeling of Cu₅FeS₄ LSPR spectra, VT-MCD at 10 T, Zeeman energy fitting with *m** acquisition description, linear *m** approximation, TEM and p-XRD for 5 nm Cu₅FeS₄ PSNCs, MCD instrument calibration using Au nanoparticles, and full unmodified VH-MCD spectra are found in the ESI (PDF)

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Author Contributions

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Notes

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